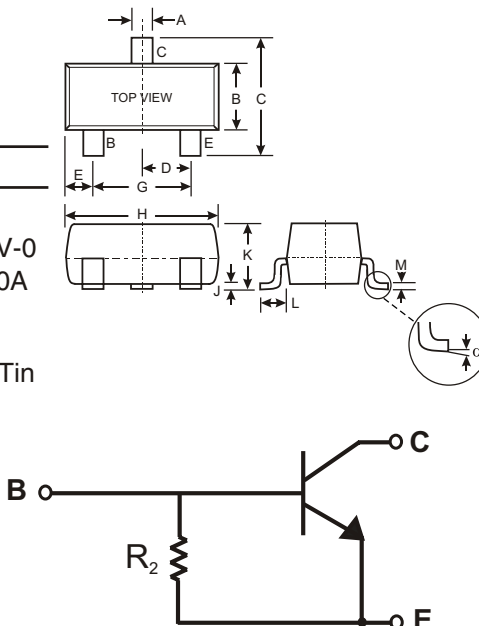


Features

- Epitaxial Planar Die Construction
- Complementary PNP Types Available (DDTA)
- Built-In Biasing Resistor, R2 only
- Also Available in Lead Free Version

Mechanical Data

- Case: SOT-23, Molded Plastic
- Case material - UL Flammability Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 3, on Page 2
- Terminal Connections: See Diagram
- Marking: Date Code and Marking Code (See Diagrams & Page 2)
- Weight: 0.008 grams (approx.)
- Ordering Information (See Page 2)



SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.85	0.80
α	0°	8°
All Dimensions in mm		

P/N	R2 (NOM)	MARKING
DDTC114GCA	10K Ω	N26
DDTC124GCA	22K Ω	N27
DDTC144GCA	47K Ω	N28
DDTC115GCA	100K Ω	N29

SCHEMATIC DIAGRAM

Maximum Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	50	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C (Max)	100	mA
Power Dissipation	P _d	200	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	R _{θJA}	625	°C/W
Operating and Storage and Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

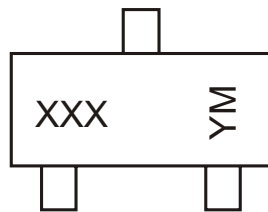
Characteristic		Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		BV_{CBO}	50	—	—	V	$I_C = 50\mu\text{A}$
Collector-Emitter Breakdown Voltage		BV_{CEO}	50	—	—	V	$I_C = 1\text{mA}$
Emitter-Base Breakdown Voltage		BV_{EBO}	5	—	—	V	$I_E = 720\mu\text{A}$, DDTC114GCA $I_E = 330\mu\text{A}$, DDTC124GCA $I_E = 160\mu\text{A}$, DDTC144GCA $I_E = 72\mu\text{A}$, DDTC115GCA
Collector Cutoff Current		I_{CBO}	—	—	0.5	μA	$V_{CB} = 50\text{V}$
Emitter Cutoff Current	DDTC114GCA DDTC124GCA DDTC144GCA DDTC115GCA	I_{EBO}	300 140 65 30	—	580 260 130 58	μA	$V_{EB} = 4\text{V}$
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	—	—	0.3	V	$I_C = 10\text{mA}$, $I_B = 0.5\text{mA}$
DC Current Transfer Ratio	DDTC114GCA DDTC124GCA DDTC144GCA DDTC115GCA	h_{FE}	30 56 68 82	—	—	—	$I_C = 5\text{mA}$, $V_{CE} = 5\text{V}$
Bleeder Resistor (R_2) Tolerance		ΔR_2	-30	—	+30	%	—
Gain-Bandwidth Product*		f_T	—	250	—	MHz	$V_{CE} = 10\text{V}$, $I_E = -5\text{mA}$, $f = 100\text{MHz}$

* Transistor - For Reference Only

Ordering Information (Note 2)

Device	Packaging	Shipping
DDTC114GCA-7	SOT-23	3000/Tape & Reel
DDTC124GCA-7	SOT-23	3000/Tape & Reel
DDTC144GCA-7	SOT-23	3000/Tape & Reel
DDTC115GCA-7	SOT-23	3000/Tape & Reel

- Notes:
- For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 - For Lead Free version (with Lead Free terminal finish) part number, please add "-F" suffix to part number above.
Example: DDTC115GCA-7-F.

Marking Information


XXX = Product Type Marking Code
 See Sheet 1 Diagrams
 YM = Date Code Marking
 Y = Year ex: N = 2002
 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009
Code	N	P	R	S	T	U	V	W

Month	Jan	Feb	March	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

TYPICAL CURVES - DDTC114GCA

NEW PRODUCT

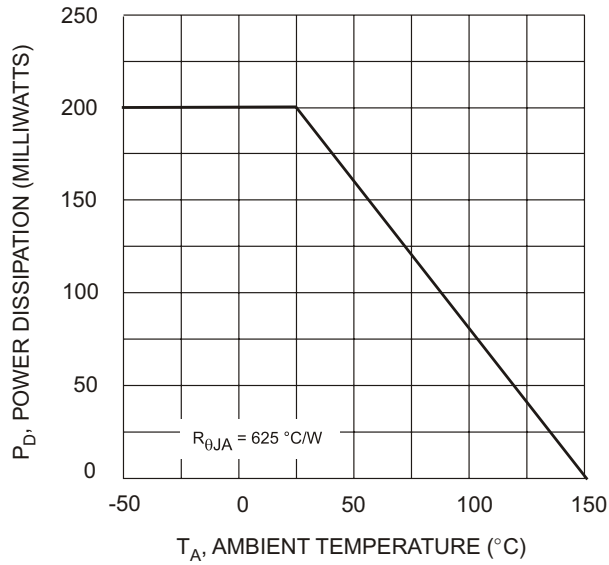


Fig. 1 Derating Curve

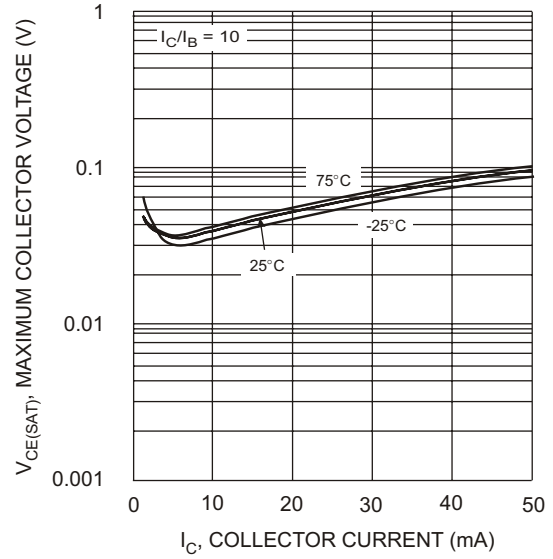
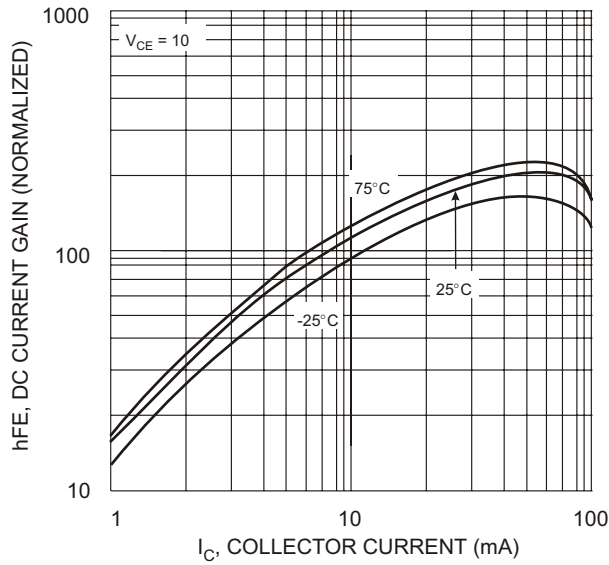

 Fig. 2 $V_{CE(SAT)}$ vs. I_C


Fig. 3 DC CURRENT GAIN

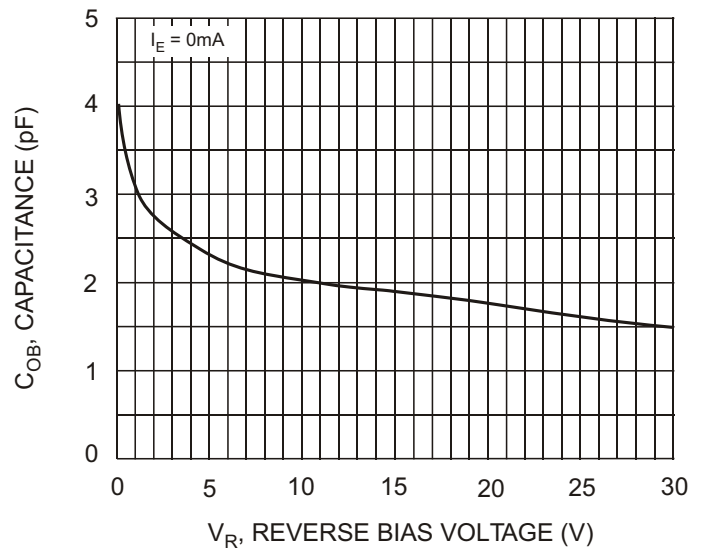


Fig. 4 Output Capacitance

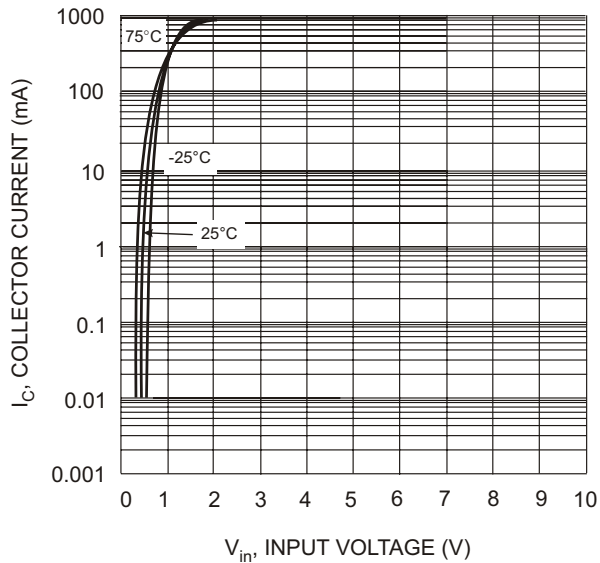


Fig. 5 Collector Current Vs. Input Voltage

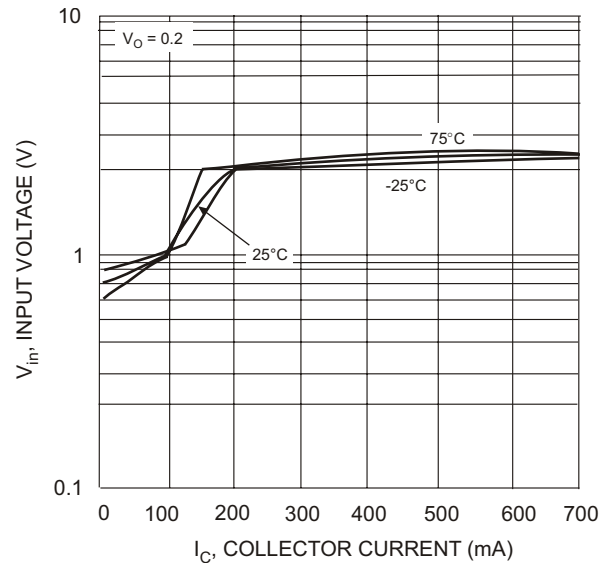


Fig. 6 Input Voltage vs. Collector Current